

# Midium Power Transistors (-80V / -2.5A)

# **2SAR544P**

#### Structure

PNP Silicon epitaxial planar transistor

#### Features

- 1) Low saturation voltage, typically  $V_{CE (sat)} = -0.4V (Max.) (I_C / I_B = -1A / -50mA)$
- 2) High speed switching

#### Applications

Driver

# Packaging specifications

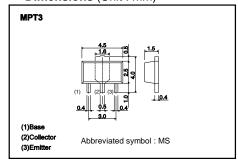
Туре	Package	Taping
	Code	T100
	Basic ordering unit (pieces)	1000
2SAR544P		0

### ● Absolute maximum ratings (Ta = 25°C)

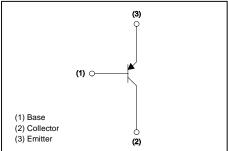
Parameter		Symbol	Limits	Unit
Collector-base voltage		$V_{CBO}$	-80	V
Collector-emitter voltage		$V_{CEO}$	-80	V
Emitter-base voltage		$V_{EBO}$	-6	V
Collector current	DC	I <sub>C</sub>	-2.5	Α
	Pulsed	I <sub>CP</sub> *1	-5	Α
Power dissipation		P <sub>D</sub> *2	0.5	W
		P <sub>D</sub> *3	2	W
Junction temperature		$T_j$	150	°C
Range of storage temperature		T <sub>stg</sub>	-55 to 150	°C

<sup>\*1</sup> Pw=10ms, Single Pulse

#### Dimensions (Unit : mm)



# • Inner circuit (Unit : mm)



<sup>\*2</sup> Each terminal mounted on a recommended land.

<sup>\*3</sup> Mounted on a ceramic board. (40x40x0.7mm³)

2SAR544P Data Sheet

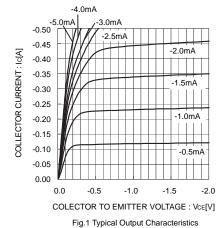
# ●Electrical characteristic (Ta = 25°C)

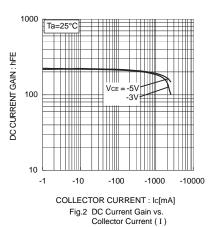
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-emitter breakdown voltage	$BV_{CEO}$	-80	-	-	V	I <sub>C</sub> = -1mA	
Collector-base breakdown voltage	$BV_{CBO}$	-80	-	-	V	I <sub>C</sub> = -100μA	
Emitter-base breakdown voltage	$BV_{EBO}$	-6	-	-	V	I <sub>E</sub> = -100μA	
Collector cut-off current	I <sub>CBO</sub>	-	-	-1	μА	V <sub>CB</sub> = -80V	
Emitter cut-off current	I <sub>EBO</sub>	-	-	-1	μA	V <sub>EB</sub> = -4V	
Collector-emitter staturation voltage	$V_{\text{CE(sat)}}$	-	-200	-400	mV	$I_{C}$ = -1A, $I_{B}$ = -50mA	
DC current gain	h <sub>FE</sub>	120	-	390	-	$V_{CE}$ = -3V, $I_{C}$ = -100mA	
Transition frequency	f <sub>⊤</sub>	1	280	1	MHz	V <sub>CE</sub> = -10V I <sub>E</sub> =500mA, f=100MHz	
Collector output capacitance	C <sub>ob</sub>	ı	32	1	pF	V <sub>CB</sub> = -10V, I <sub>E</sub> =0A f=1MHz	
Turn-on time	t <sub>on</sub> * <sub>1</sub>	-	50	-	ns	I - 1 2 \ I - 120m \	
Storage time	t <sub>stg</sub> * <sub>1</sub>	-	400	-	ns	$I_{C}$ = -1.3A, $I_{B1}$ = -130mA, $I_{B2}$ =130mA, $V_{CC}$ ~-10V	
Fall time	t <sub>f</sub> *1	-	40	-	ns	16Z=1001111 1, VCC _ 10V	

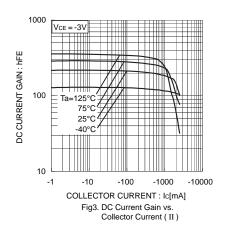
<sup>\*1</sup> See switching time test circuit

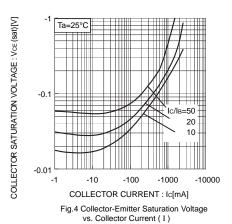
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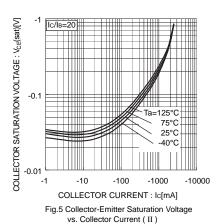
#### •Electrical characteristic curves

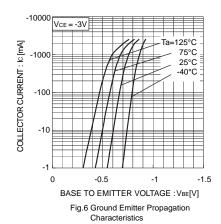


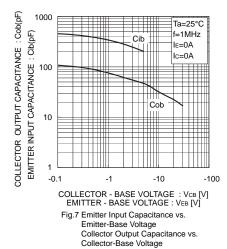












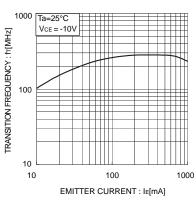
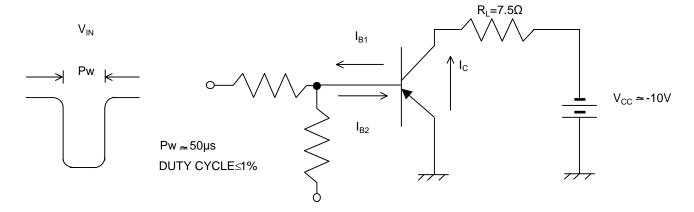
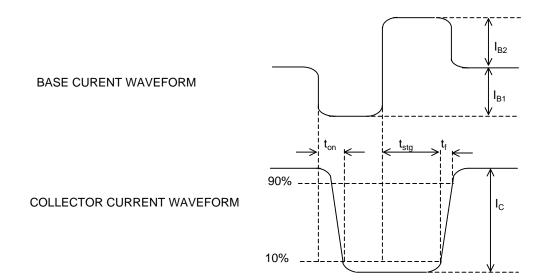


Fig.8 Gain Bandwidth Product vs. Emitter Current

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# •Switching time test circuit





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